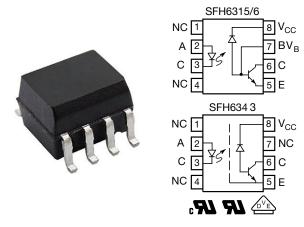


High Speed Optocoupler, 1 MBd, Transistor Output



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The SFH6315, SFH6316, SFH6343, high speed optocouplers, each consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector and a high speed transistor. The photo detector is junction isolated from the transistor to reduce miller capacitance effects. The open collector output function allows circuit designers to adjust the load conditions when interfacing with different logic systems such as TTL, CMOS, etc.

Because the SFH6343 has a faraday shield on the detector chip, it can also reject and minimize high input to output common mode transient voltages. The SFH6343 provides an isolated base connection to further reduce the potential electrical noise entering the package.

FEATURES

- Surface mountable
- Compatible with infrared vapor phase reflow and wave soldering processes
- Isolation test voltage, 4000 V_{RMS}
- Very high common mode transient immunity: 15000 V/µs at V_{CM} = 1500 V guaranteed (SFH6343)



- High speed: 1 MBd
- Guaranteed AC and DC performance temperature: 0 °C to 70 °C
- Open collector output
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Microprocessor system interface
- · Ground loop elimination
- Galvanic noise isolation
- · Serial bus systems
- · Signal level translation

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884), available with option 1

ORDERING INFORMATION						
S F H	6 3 PART NUMBER	# # T	SOIC-8			
AGENCY CERTIFIED / PACKAGE		CTR (%)				
UL, cUL	≥ 5	≥ 15	NO BASE CONNECTION			
SOIC-8	SFH6315T	SFH6316T	SFH6343T			



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V_R	3	V		
DC forward current		I _F	25	mA		
Surge forward current	$t_p \le 1 \mu s$, 300 pulses/s	I _{FSM}	1	Α		
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	45	mW		
OUTPUT						
Supply voltage		Vs	-0.5 to 30	V		
Output voltage		Vo	-0.5 to 25	V		
Output current		Io	8	mA		
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	100	mW		
COUPLER						
Storage temperature range		T _{stg}	-55 to +150	°C		
Ambient temperature range		T _{amb}	-55 to +100	°C		
Junction temperature		Tj	125	°C		
Soldering temperature	Max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm		260	°C		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

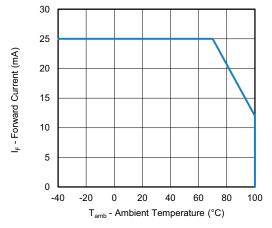


Fig. 1 - Forward Current vs. Ambient Temperature

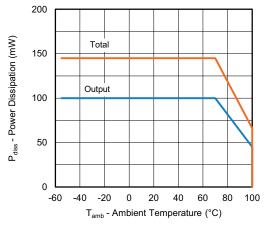


Fig. 2 - Power Dissipation vs. Ambient Temperature



PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Famusard valtage	I _F = 16 mA ⁽¹⁾		V_{F}	-	1.3	1.8	V
Forward voltage	I _F = 16 mA		V_{F}	-	1.3	1.9	V
Reverse current	V _R = 3 V		I _R	-	0.001	10	μΑ
Capacitance	$f = 1 \text{ MHz}, V_F = 0 \text{ V}$		C _{IN}	-	24	-	pF
Temperature coefficient of forward voltage	I _F = 16 mA		$\Delta V_F/\Delta T_{amb}$	-	-1.7	-	mW/°C
ОИТРИТ							
Logic low supply current	$I_F = 16 \text{ mA}, V_O = \text{open}, V_{CC} = 15 \text{ V}$		I _{CCL}	-	215	-	μΑ
	$I_F = 0$ mA, $V_O = open$, $V_{CC} = 15 V (1)$		I _{CCH}	-	0.1	1	μΑ
Logic high supply current	$I_F = 0$ mA, $V_O = open$, $V_{CC} = 15$ V		Icch	-	0.1	2	μΑ
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 1.1 \text{ mA}^{(1)}$	SFH6315	V _{OL}	-	0.15	0.4	V
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 0.8 \text{ mA}$		V _{OL}	-	0.13	0.5	V
Lagia law autaut valtaga	$I_F = 16$ mA, $V_{CC} = 4.5$ V, $I_O = 3$ mA $^{(1)}$	SFH6316	V _{OL}	-	0.25	0.4	V
Logic low output voltage	I _F = 16 mA, V _{CC} = 4.5 V, I _O = 2.4 mA	SFH0310	V _{OL}	-	0.22	0.5	V
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 3.0 \text{ mA}^{(1)}$	SFH6343	V _{OL}	-	0.25	0.4	V
	I _F = 16 mA, V _{CC} = 4.5 V, I _O = 2.4 mA	SFH0343	V _{OL}	-	0.22	0.5	V
Logic high output current	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}^{(1)}$		I _{OH}	-	0.003	0.5	μΑ
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}^{(1)}$		I _{OH}	-	0.01	1	μΑ
	I _F = 0 mA, V _O = V _{CC} = 15 V		I _{OH}	ı	-	50	μΑ
COUPLER							
Capacitance (input to output) (2)	f = 1 MHz		C _{IO}	-	0.4	-	pF

Notes

 $^{^{(2)}\,}$ A 0.1 μF bypass capacitor connected between pins 5 and 8 is recommended

CURRENT TRANSFER RATIO (T _{amb} = 0 °C to 70 °C; typical values are at T _{amb} = 25 °C)							
PARAMETER	TEST CONDITION		SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 16 mA, V _O = 0.4 V, V _{CC} = 4.5 V ⁽¹⁾ SFH6315	7	28	50	%		
Current transfer ratio	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V}, V_{CC} = 4.5 \text{ V}$	3500313	CTR	5	29	-	%
	$I_F = 16$ mA, $V_O = 0.4$ V, $V_{CC} = 4.5$ V $^{(1)}$	SFH6316	CTR	19	28	50	%
	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V}, V_{CC} = 4.5 \text{ V}$	3510310	CTR	15	29	-	%
	I_F = 16 mA, V_O = 0.4 V, V_{CC} = 4.5 V $^{(1)}$	SFH6343	CTR	19	28	50	%
	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V}, V_{CC} = 4.5 \text{ V}$	3FF10343	CTR	15	29	-	%

Notes

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

⁽¹⁾ $T_{amb} = 25 \, ^{\circ}C$

[•] Current transfer ratio in percent equals the ratio of output collector current (I_O) to the forward LED input current (I_F) times 100. A 0.1 µF bypass capacitor connected between pins 5 and 8 is recommended.

 $^{^{(1)}}$ $T_{amb} = 25 \, ^{\circ}C$

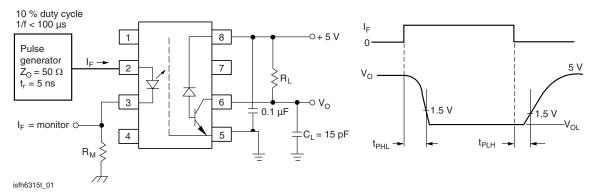


Fig. 3 - Test Circuit for Switching Times

SWITCHING CHARACTERISTICS $(T_{amb} = 0 ^{\circ}\text{C to } 70 ^{\circ}\text{C}, V_{CC} = 5 \text{V}, I_{F} = 16 \text{mA}; \text{typical values are at } T_{amb} = 25 ^{\circ}\text{C})$								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Propagation delay time to logic low at output (see Fig. 1)	$R_L = 4.1 \text{ k}\Omega$	SFH6315	t _{PHL} (1)	-	0.5	1.5	μs	
		SFH0313	t _{PHL}	-	0.5	2	μs	
	$R_L = 1.9 \text{ k}\Omega$	SFH6316,	t _{PHL} (1)	-	0.6	0.8	μs	
		SFH6343	t _{PHL}	-	0.6	1	μs	
	R _L = 4.1 kΩ	SFH6315	t _{PLH} (1)	-	0.7	1.5	μs	
Propagation delay time to logic high at output (see Fig. 1)			t _{PLH}	-	0.7	2	μs	
	$B_i = 1.0 \text{ k}$	SFH6316,	t _{PLH} (1)	-	0.3	0.8	μs	
		SFH6343	t _{PLH}	-	0.3	1	μs	

Notes

The 1.9 kΩ load represents 1 TTL unit load of 1.6 mA and the 5.6 kΩ pull-up resistor.
 The 4.1 kΩ load represents 1 LSTTL unit load of 0.36 mA and the 6.1 kΩ pull-up resistor.

 $^{^{(1)}}$ $T_{amb} = 25$ $^{\circ}C$

COMMON MODE TRANSIENT IMMUNITY ($T_{amb} = 25 ^{\circ}C$)							
PARAMETER	TEST CONDITION PART SYMBOL MIN. TYP. M.						UNIT
Common mode transient	$R_L = 4.1 \text{ k}\Omega, I_F = 0 \text{ mA}, V_{CM} = 10 V_{PP}$	SFH6315	CM _H	-	1000	-	V/µs
immunity at logic high level output (see Fig. 2)	$R_L = 1.9 \text{ k}\Omega, I_F = 0 \text{ mA}, V_{CM} = 10 \text{ V}_{PP}$	SFH6316	CM _H	-	1000	-	V/µs
	$R_L = 1.9 \text{ k}\Omega, I_F = 0 \text{ mA}, V_{CM} = 1500 \text{ V}_{PP}$	SFH6343	CM _H	15 000	30 000	-	V/µs
Common mode transient	$R_L = 4.1 \text{ k}\Omega$, $I_F = 16 \text{ mA}$, $V_{CM} = 10 \text{ V}_{PP}$	SFH6315	CM _L	-	1000	-	V/µs
immunity at logic low level output (see Fig. 2)	$R_L = 1.9 \text{ k}\Omega$, $I_F = 16 \text{ mA}$, $V_{CM} = 10 \text{ V}_{PP}$	SFH6316	CM _L	-	1000	-	V/µs
	$R_L = 1.9 \text{ k}\Omega, I_F = 16 \text{ mA}, V_{CM} = 1500 \text{ V}_{PP}$	SFH6343	CM _L	15 000	30 000	-	V/µs

Note

Common mode transient immunity in a logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode
pulse (V_{CM}) to assure that the output will remain in a logic high state (i.e., V_O > 2 V). Common mode transient immunity in a logic low level
the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal (V_{CM} to assure that the output will remain
in logic low state, i.e., V_O < 0.8 V).

The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and the 5.6 k Ω pull-up resistor.

The 4.1 k Ω load represents 1 LSTTL unit load of 0.36 mA and the 6.1 k Ω pull-up resistor.

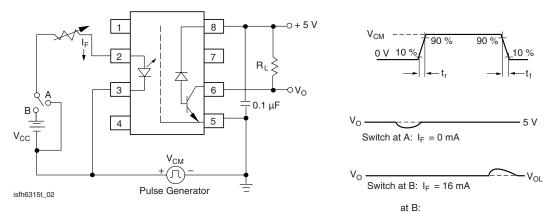


Fig. 4 - Test Circuit for Transient Immunity and Typical Waveforms

PARAMETER	TEST CONDITION	SYMBOL	MIN.	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	4000	V_{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	6000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	560	V _{peak}
Isolation resistance	$T_{amb} = 25 ^{\circ}C, V_{IO} = 500 V$	R _{IO}	≥ 10 ¹²	Ω
isolation resistance	T _{amb} = 100 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	350	mW
Input safety current		I _{SI}	150	mA
Input safety temperature		T _S	165	°C
Creepage distance	5010.8		≥ 4	mm
Clearance distance	SOIC-8		≥ 4	mm
Insulation thickness		DTI	≥ 0.2	mm

Notes

As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

⁽¹⁾ Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

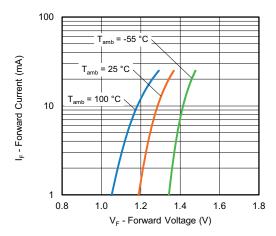


Fig. 5 - Forward Current vs. Forward Voltage

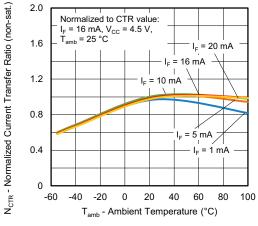


Fig. 6 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

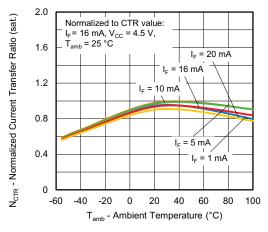


Fig. 7 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

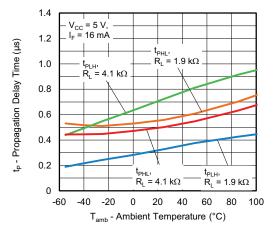


Fig. 8 - Propagation Delay Time vs. Ambient Temperature

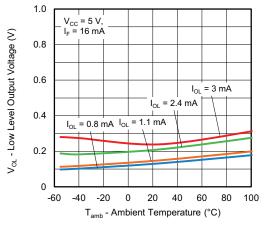
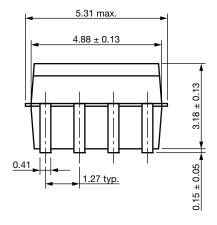
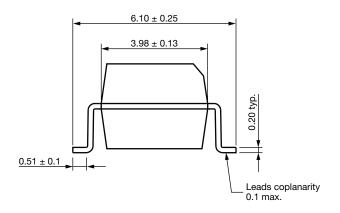
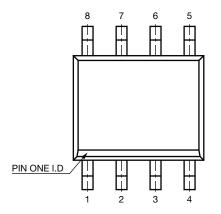


Fig. 9 - Low Level Output Voltage vs. Ambient Temperature

PACKAGE DIMENSIONS (in millimeters)









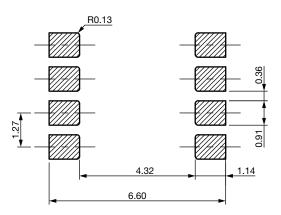


Fig. 10 - Package Drawing

PACKAGE MARKING

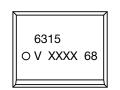


Fig. 11 - Example of SFH6315T

Notes

- XXXX = LMC (lot marking code)
- Tape and reel suffix (T) is not part of the package marking

PACKING INFORMATION (in millimeters)

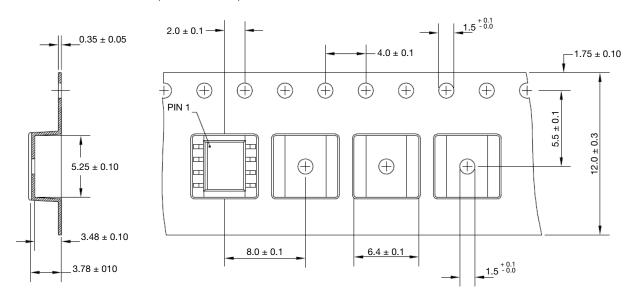


Fig. 12 - Tape and Reel Packing (2000 pieces on reel)

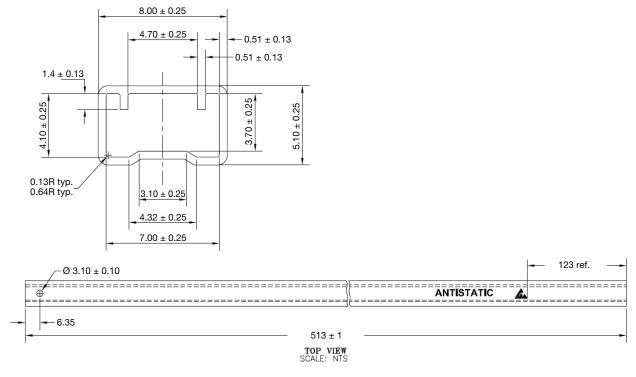


Fig. 13 - Tube Packing

DEVICE PER TUBE							
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX				
SOIC-8	100	30	3000				



SOLDER PROFILES

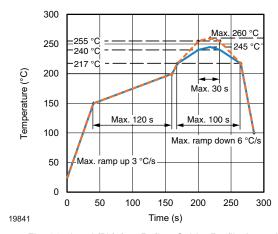


Fig. 14 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 1C Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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